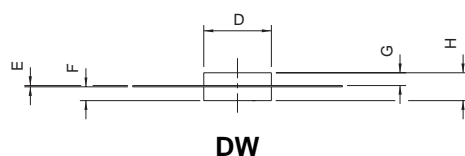
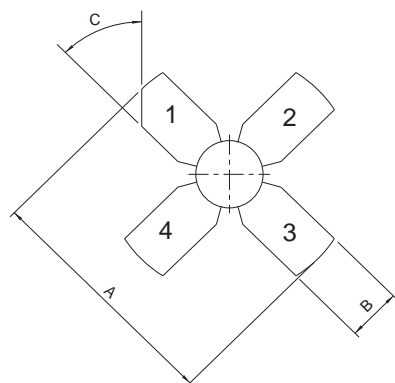


MECHANICAL DATA



PIN 1 DRAIN                      PIN 2 SOURCE  
 PIN 3 GATE                      PIN 4 SOURCE

DIM	mm	Tol.	Inches	Tol.
A	26.16	0.38	1.030	0.015
B	5.72	0.13	0.225	0.005
C	45°	5°	45°	5°
D	7.11	0.13	0.280	0.005
E	0.13	0.03	0.005	0.001
F	1.52	0.13	0.055	0.005
G	0.43	0.20	0.060	0.008
H	7.67	REF	0.120	REF

**GOLD METALLISED  
 MULTI-PURPOSE SILICON  
 DMOS RF FET  
 10W – 12.5V – 175MHz  
 SINGLE ENDED**

**FEATURES**

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW  $C_{rss}$
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN – 10 dB MINIMUM

**APPLICATIONS**

- HF/VHF/UHF COMMUNICATIONS  
 from 1 MHz to 175 MHz

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

$P_D$	Power Dissipation	50W
$BV_{DSS}$	Drain – Source Breakdown Voltage	40V
$BV_{GSS}$	Gate – Source Breakdown Voltage	$\pm 20V$
$I_{D(sat)}$	Drain Current	10A
$T_{stg}$	Storage Temperature	$-65$ to $150^{\circ}C$
$T_j$	Maximum Operating Junction Temperature	$200^{\circ}C$

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

## ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
B <sub>V</sub> DSS Drain–Source Breakdown Voltage	V <sub>GS</sub> = 0      I <sub>D</sub> = 100mA	40			V
I <sub>D</sub> DSS Zero Gate Voltage Drain Current	V <sub>DS</sub> = 12.5V      V <sub>GS</sub> = 0			1	mA
I <sub>G</sub> DSS Gate Leakage Current	V <sub>GS</sub> = 20V      V <sub>DS</sub> = 0			1	μA
V <sub>GS(th)</sub> Gate Threshold Voltage*	I <sub>D</sub> = 10mA      V <sub>DS</sub> = V <sub>GS</sub>	1		7	V
g <sub>fs</sub> Forward Transconductance*	V <sub>DS</sub> = 10V      I <sub>D</sub> = 1A	0.8			S
G <sub>PS</sub> Common Source Power Gain	P <sub>O</sub> = 10W	10			dB
η Drain Efficiency	V <sub>DS</sub> = 12.5V      I <sub>DQ</sub> = 0.4A	50			%
VSWR Load Mismatch Tolerance	f = 175MHz	20:1			—
C <sub>iss</sub> Input Capacitance	V <sub>DS</sub> = 0      V <sub>GS</sub> = -5V      f = 1MHz			60	pF
C <sub>oss</sub> Output Capacitance	V <sub>DS</sub> = 12.5V      V <sub>GS</sub> = 0      f = 1MHz			40	pF
C <sub>rss</sub> Reverse Transfer Capacitance	V <sub>DS</sub> = 12.5V      V <sub>GS</sub> = 0      f = 1MHz			4	pF

\* Pulse Test:    Pulse Duration = 300 μs , Duty Cycle ≤ 2%

## HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

**THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.**

## THERMAL DATA

R <sub>THj-case</sub>	Thermal Resistance Junction – Case	Max. 3.5°C / W
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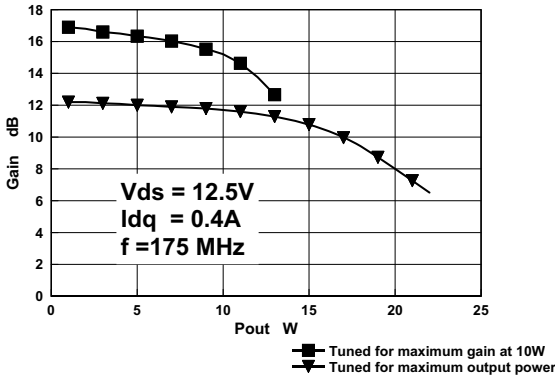


Figure 1 – Gain vs. Power Output.

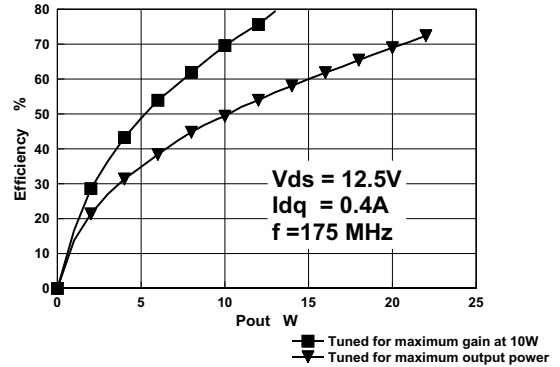


Figure 2 – Efficiency vs. Power Output.

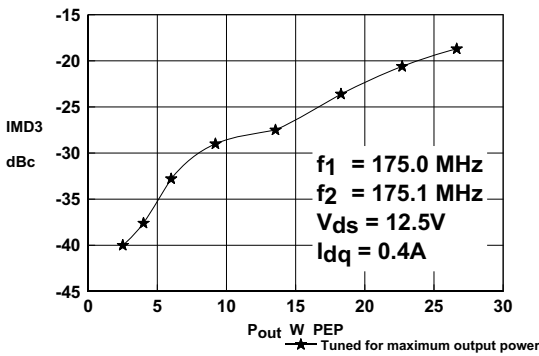


Figure 3 – IMD vs. Power Output.

D1221UK  
OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	Z <sub>S</sub> Ω	Z <sub>L</sub> Ω
175MHz	7.2 + j15	4.1 - j2.5

Typical S Parameters

! V<sub>DS</sub> = 12.5V, I<sub>DQ</sub> = 0.4A  
# MHZ S MA R 50

!Freq !Mhz	S11		S21		S12		S22	
	mag	ang	mag	ang	mag	ang	mag	ang
50	0.7	-116.5	14.93	97.9	0.036	15.7	0.64	-108.4
100	0.7	-140	7.42	73.6	0.03	2.7	0.65	-132
150	0.75	-150.2	4.56	58.1	0.02	11	0.71	-143.1
200	0.81	-157.2	3.1	46.5	0.016	52.3	0.78	-151.2
250	0.85	-163.1	2.23	37.4	0.026	82.6	0.83	-157.9
300	0.88	-168.1	1.67	30.3	0.04	90.1	0.86	-163.7
350	0.9	-172.6	1.3	24.7	0.055	90.8	0.89	-168.8
400	0.92	-176.6	1.04	20.3	0.071	89.2	0.91	-173.4
450	0.93	-179.7	0.85	17.1	0.086	86.8	0.92	-177.5
500	0.94	-176.3	0.71	14.9	0.101	84.2	0.93	-178.7
550	0.95	-173.1	0.6	13.5	0.115	81.5	0.94	-175.2
600	0.95	-170.1	0.52	13.0	0.130	78.8	0.95	-171.9

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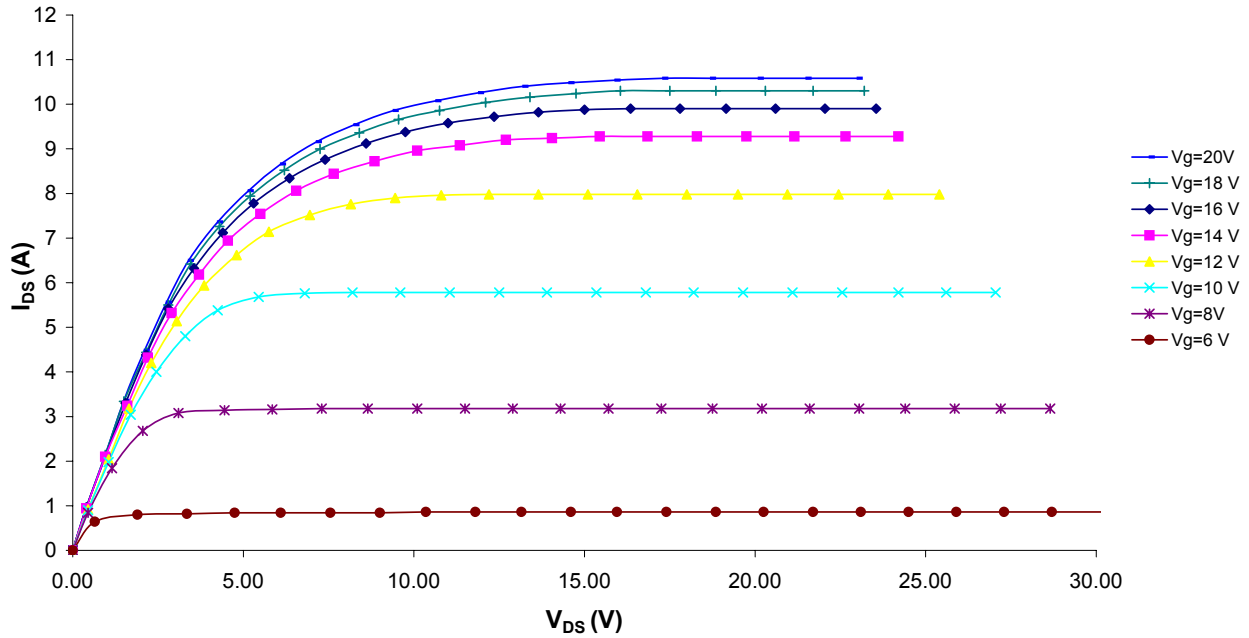


Figure 4 – Typical IV Characteristics.

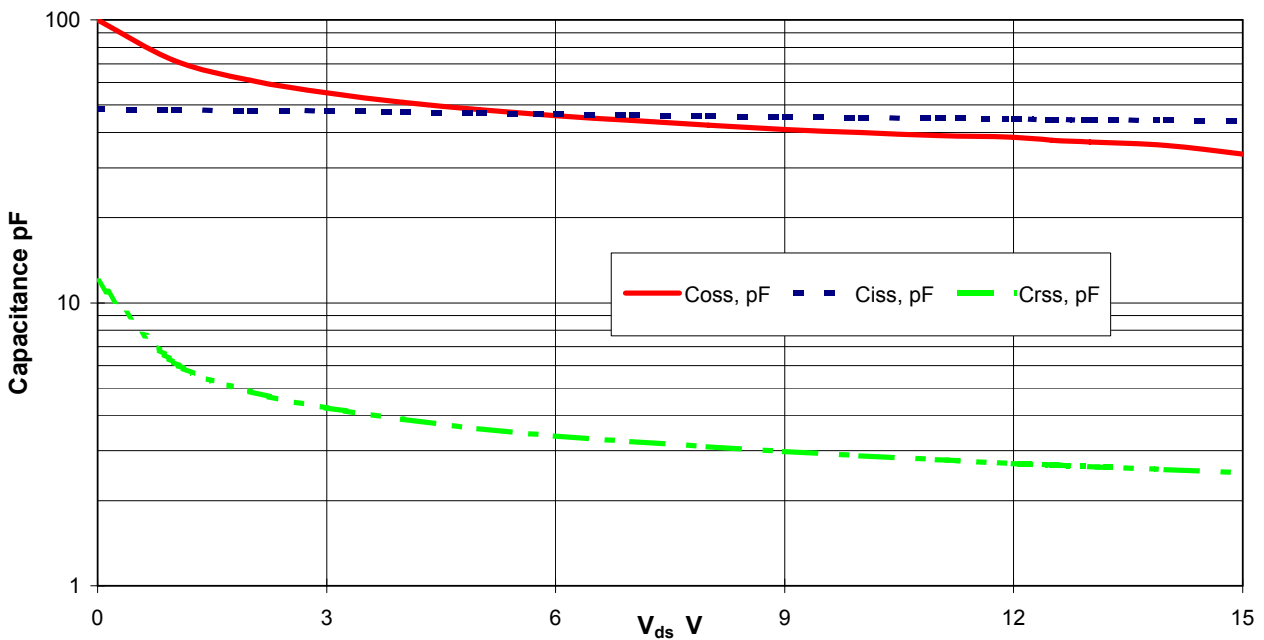


Figure 5 – Typical CV Characteristics.

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